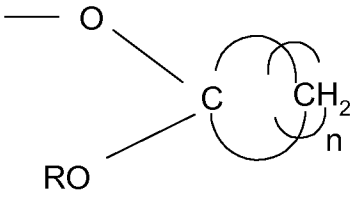
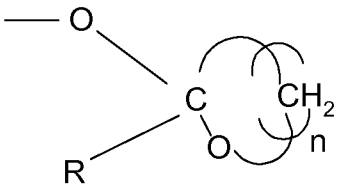
AMENDMENTS TO THE CLAIMS:

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) A resist composition, said composition comprising an acid-sensitive imaging polymer including a silsesquioxane backbone and a solubility inhibiting cyclic ketal pendant acid-labile moiety having a low activation energy less than about 20 kcal/mol for acid-catalyzed cleaving, wherein said acid-labile moiety is cleavable at room temperature, and wherein said cyclic ketal acid-labile moiety comprises a structure of the form



or



where n is any integer from 2 to 15 and R is an alkyl or a halogenated alkyl, and wherein at least a portion of said imaging polymer is fluorinated and said imaging polymer further comprises a pendant solubility promoting moiety selected from the group consisting of a fluoroalcohol, a carboxylic acid, an amino group, an imino group, a fluorinated imino group and a fluorinated amino group, wherein said pendant solubility promoting moiety is protected with said cyclic ketal acid-labile moiety, and wherein at least a portion of said solubility inhibiting cyclic ketal acid-labile moiety is fluorinated and

is substituted with a hydrophobic moiety selected from the group consisting of —CF_3, —CHF_2, —CH_2F, —CCl_3, —$CHCl_2$ and —CH_2Cl, and —$Si(CH_3)_3$.

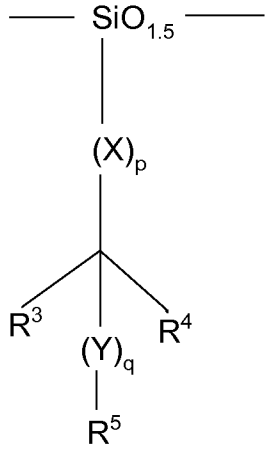
2. (Original) The resist composition of claim 1, further comprising a radiation-sensitive acid generator.

3-9. (Canceled)

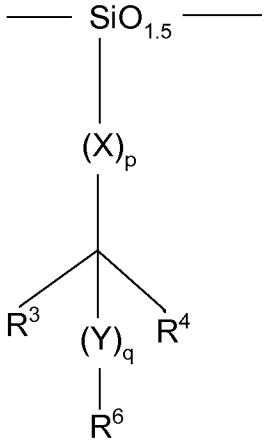
10. (Currently Amended) The resist composition of claim [[3]] 1, wherein at least a portion of said solubility promoting moiety is fluorinated.

11. (Original) The resist composition of claim 1, wherein said silsesquioxane polymer has a weight average molecular weight of about 800 to 500,000.

12. (Previously Presented) The resist composition of claim 1, wherein said imaging polymer comprises a combination of monomeric units (II) and (III) described by the formulas:



(II) and



(III)

in which

each R^3 is independently selected from the group consisting of a hydrogen atom, a halogen atom, a linear alkyl, a branched alkyl, a cycloalkyl, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl, a halogenated aryl, or any combination thereof,

each X is independently selected from the group consisting of an oxygen atom, a sulfur atom, NR^3, a linear alkyl, a branched alkyl, a cycloalkyl group, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl group, or a halogenated aryl, wherein p is an integer having the value 1 or 0,

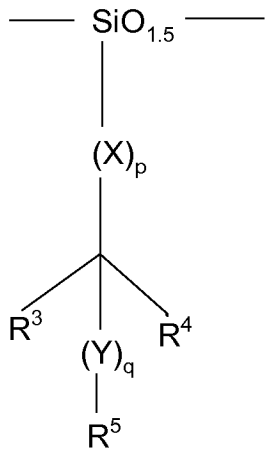
each Y is independently selected from the group consisting of a linear alkyl, a branched alkyl, a cycloalkyl group, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl group, or a halogenated aryl, wherein q is an integer having the value 1 or 0,

each R^4 is independently selected from the group consisting of a fluorine atom, a fluorinated linear alkyl, a fluorinated branched alkyl, a fluorocycloalkyl, a fluoroaryl, or any combination thereof,

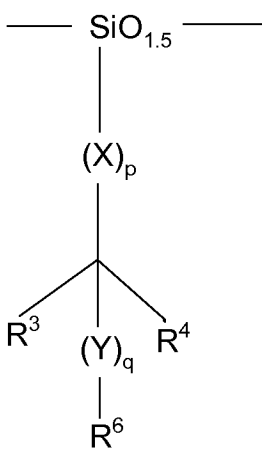
each R^5 is independently a solubility inhibiting cyclic ketal group, and

each R^6 consists of said pendant solubility promoting moiety, wherein said pendant solubility promoting moiety is protected with said cyclic ketal acid-labile moiety.

13. (Previously Presented) The resist composition of claim 1, wherein said imaging polymer comprises a combination of monomeric units (III) and (IV) or units (II) and (V), wherein the monomeric units (II) and (III) are described by the formulas:



(II) and



(III)

in which

each R^3 is independently selected from the group consisting of a hydrogen atom, a halogen atom, a linear alkyl, a branched alkyl, a cycloalkyl, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl, a halogenated aryl, or any combination thereof,

each X is independently selected from the group consisting of an oxygen atom, a sulfur atom, NR^3, a linear alkyl, a branched alkyl, a cycloalkyl group, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl group, or a halogenated aryl, wherein p is an integer having the value 1 or 0,

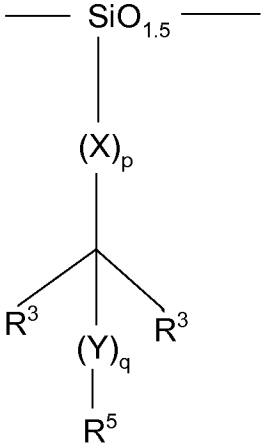
each Y is independently selected from the group consisting of a linear alkyl, a branched alkyl, a cycloalkyl group, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl group, or a halogenated aryl, wherein q is an integer having the value 1 or 0,

each R^4 is independently selected from the group consisting of a fluorine atom, a fluorinated linear alkyl, fluorinated branched alkyl, a fluorocycloalkyl, a fluoroaryl, or any combination thereof,

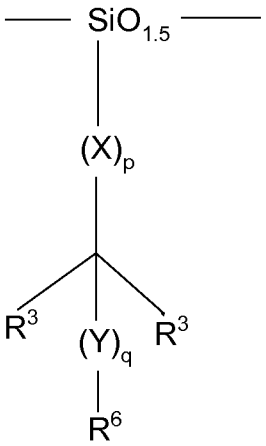
each R^5 is independently a solubility inhibiting cyclic ketal group, and

each R^6 consists of said pendant solubility promoting moiety, wherein said pendant solubility promoting moiety is protected with said cyclic ketal acid-labile moiety; and

the monomeric units (IV) and (V) are described by the formulas:



(IV) and

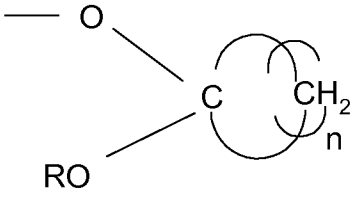


(V).

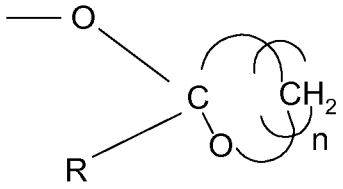
14. (Currently Amended) A method of forming a structure on a substrate, said method comprising the steps of:

providing a substrate;

applying a resist composition to said substrate to form a resist layer on said substrate, said resist composition comprising an acid-sensitive imaging polymer comprising a silsesquioxane backbone, and a solubility inhibiting pendant cyclic ketal acid-labile moiety having a low activation energy less than about 20 kcal/mol for acid-catalyzed cleaving, wherein said acid-labile moiety is cleavable at room temperature, and wherein said cyclic ketal acid-labile moiety comprises a structure of the form



or



where n is any integer from 2 to 15 and R is an alkyl or a halogenated alkyl, and wherein at least a portion of said imaging polymer is fluorinated and said imaging polymer further comprises a pendant solubility promoting moiety selected from the group consisting of a fluoroalcohol, a carboxylic acid, an amino group, an imino group, a fluorinated imino group and a fluorinated amino group, wherein said pendant solubility promoting moiety is protected with said cyclic ketal acid-labile moiety, and wherein at least a portion of said solubility inhibiting cyclic ketal acid-labile moiety is fluorinated and is substituted with a hydrophobic moiety selected from the group consisting of —CF_3, —CHF_2, —CH_2F, —CCl_3, —$CHCl_2$ and —CH_2Cl, and —$Si(CH_3)_3$; and

patternwise exposing said substrate to radiation, whereby acid is generated by said radiation-sensitive acid generator in exposed regions of said resist layer;

removing patternwise soluble portions of said resist layer to form a pattern of spaces in said resist layer; and

transferring said pattern of spaces to said substrate.

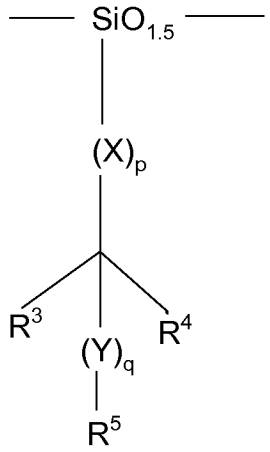
15. (Original) The method of claim 14 further comprising the step of baking the exposed resist layer to promote acid-catalyzed reaction in exposed portions of said resist layer.

16. (Original) The method of claim 14 wherein said resist composition further comprises a radiation-sensitive acid generator.

17-23. (Canceled)

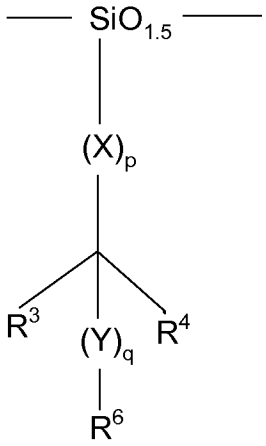
24. (Original) The method of claim 14, wherein said silsesquioxane polymer has a weight average molecular weight of about 800 to 500,000.

25. (Previously Presented) The method of claim 14, wherein said imaging polymer comprises a combination of monomeric units (II) and (III) described by the formulas:



(II)

and



(III)

in which

each R^3 is independently selected from the group consisting of a hydrogen atom, a halogen atom, a linear alkyl, a branched alkyl, a cycloalkyl, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl, a halogenated aryl, or any combination thereof,

each X is independently selected from the group consisting of an oxygen atom, a sulfur atom, NR^3, a linear alkyl, a branched alkyl, a cycloalkyl, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl group, or a halogenated aryl, wherein p is an integer having the value 1 or 0,

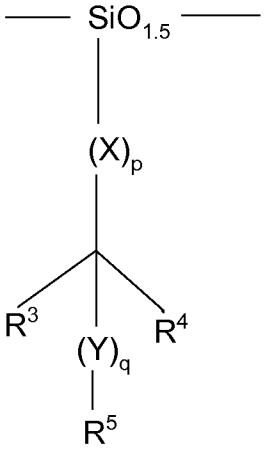
each Y is selected from the group consisting of a linear alkyl, a branched alkyl, a cycloalkyl group, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl group, or a halogenated aryl, wherein q is an integer having the value 1 or 0,

each R^4 is selected from the group consisting of a fluorine atom, a fluorinated linear alkyl, a fluorinated branched alkyl, a fluorocycloalkyl, a fluoroaryl, or any combination thereof,

each R^5 is independently a cyclic ketal solubility inhibiting group, and

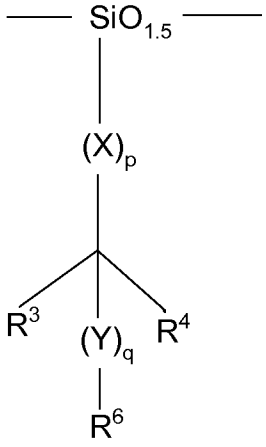
each R^6 consists of said pendant solubility promoting moiety, wherein said pendant solubility promoting moiety is protected with said cyclic ketal acid-labile moiety.

26. (Previously Presented) The method of claim 14, wherein said imaging polymer comprises a combination of monomeric units (III) and (IV) or units (II) and (V), wherein the monomeric units (II) and (III) are described by the formulas:



(II)

and



(III)

in which

each R^3 is independently selected from the group consisting of a hydrogen atom, a halogen atom, a linear alkyl, a branched alkyl, a cycloalkyl, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl, a halogenated aryl, or any combination thereof,

each X is selected from the group consisting of an oxygen atom, a sulfur atom, NR^3, a linear alkyl, a branched alkyl, a cycloalkyl group, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl group, or a halogenated aryl, wherein p is an integer having the value 1 or 0,

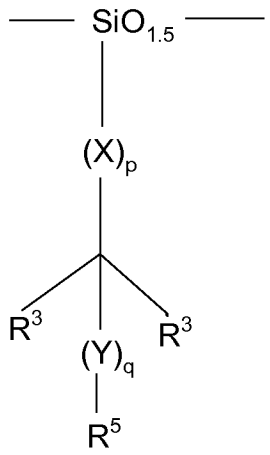
each Y is selected from the group consisting of a linear alkyl, a branched alkyl, a cycloalkyl group, a halogenated linear alkyl, a halogenated branched alkyl, a halogenated cycloalkyl, an aryl group, or a halogenated aryl, wherein q is an integer having the value 1 or 0,

each R^4 is independently selected from the group consisting of a fluorine atom, a fluorinated linear alkyl, a fluorinated branched alkyl, a fluorocycloalkyl, a fluoroaryl, or any combination thereof,

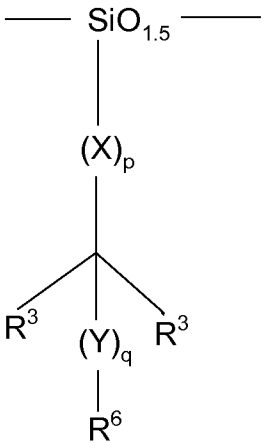
each R^5 is independently a cyclic ketal solubility inhibiting group, and

each R^6 consists of said pendant solubility promoting moiety, wherein said pendant solubility promoting moiety is protected with said cyclic ketal acid-labile moiety; and

the monomeric units (IV) and (V) are described by the formulas:



(IV) and



(V).

27. (Original) The method of claim 14, further comprising forming a planarizing layer over said substrate, wherein said resist layer is applied directly to said planarizing layer, and etching said planarizing layer through said pattern of spaces in said resist layer to expose said substrate.

28. (Original) The method of claim 27, wherein said planarizing layer has an underlayer composition comprising:

(A) a polymer containing (i) cyclic ether moieties, (ii) saturated polycyclic moieties, and (iii) aromatic moieties if said underlayer composition does not require a separate crosslinker, or

(B) a polymer containing (i) saturated polycyclic moieties, and (ii) aromatic moieties if said underlayer composition requires a separate crosslinker.

29. (Original) The method of claim 28, wherein said underlayer composition further comprises a fluorinated polycyclic moiety, a fluorinated aromatic moiety or a combination thereof.

30. (Original) The method of claim 14, wherein said step of transferring further comprises a method selected from the group consisting of depositing, implanting, plating and etching.